

Photointerrupter, Ultraminiature SMD type



Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Input (LED)	Forward current	I_F	50	mA
	Reverse voltage	V_R	5	V
	Power dissipation	P_D	80	mW
Output (photo-transistor)	Collector-emitter voltage	V_{CEO}	30	V
	Emitter-collector voltage	V_{ECO}	4.5	V
	Collector current	I_C	30	mA
	Collector power dissipation	P_C	80	mW
	Operating temperature	T_{opr}	-25 to +85	°C
Storage temperature		T_{stg}	-30 to +85	°C

Applications

DSC(Digital steal camera)
DVC(Digital video camera)
Digital handy phone

Features

- 1) Ultraminiature SMD type.
- 2) Gap 1.2mm.

Electrical and optical characteristics (Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input characteristics	Forward voltage	V_F	—	1.3	1.6	V	$I_F=50\text{mA}$
	Reverse current	I_R	—	—	10	μA	$V_R=5\text{V}$
Output characteristics	Dark current	I_{CEO}	—	—	0.5	μA	$V_{CE}=10\text{V}$
	Peak sensitivity wavelength	λ_P	—	800	—	nm	—
Transfer characteristics	Collector current	I_C	0.95	—	4.95	mA	$V_{CE}=5\text{V}, I_F=20\text{mA}$
	Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	0.4	V	$I_F=20\text{mA}, I_C=0.1\text{mA}$
	Response time	Rise time	—	10	—	μs	$V_{CC}=5\text{V}, I_F=20\text{mA}, R_L=100\Omega$
		Fall time	—	10	—	μs	
Infrared light emitter diode	Cut-off frequency	f_c	—	1	—	MHz	$I_F=50\text{mA}$ * Non-coherent Infrared light emitting diode used.
	Peak light emitting wavelength	λ_P	—	950	—	nm	—
Photo transistor	Response time	$tr \cdot tf$	—	10	—	μs	$V_{CC}=5\text{V}, I_C=1\text{mA}, R_L=100\Omega$ * This product is not designed to be protected against electromagnetic wave.
	Maximum sensitivity wavelength	λ_P	—	800	—	nm	—

Electrical and optical characteristics curves

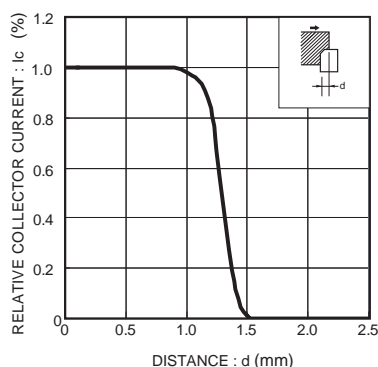


Fig.1 Relative output current vs. distance (I)

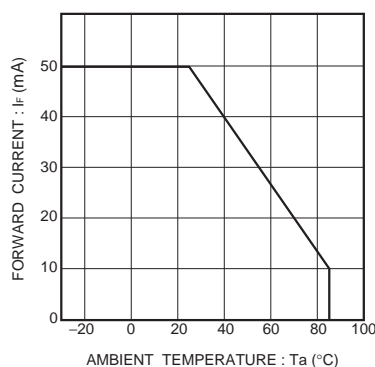


Fig.2 Forward current falloff

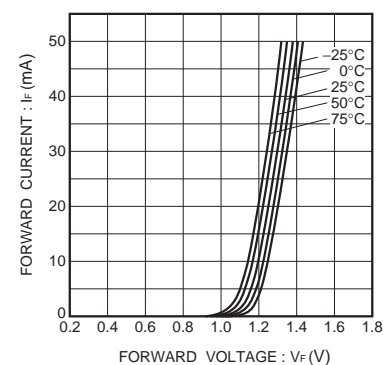


Fig.3 Forward current vs. forward voltage

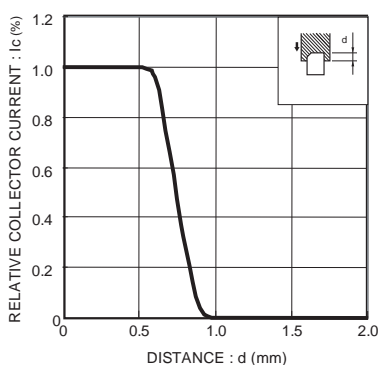


Fig.4 Relative output current vs. distance (II)

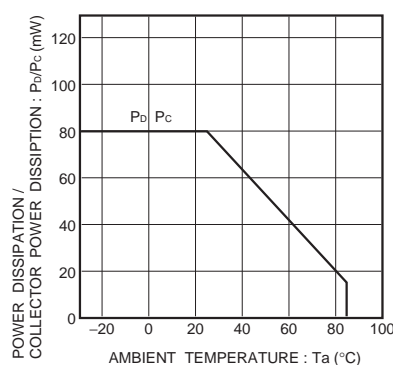


Fig.5 Power dissipation / collector power dissipation vs. ambient temperature

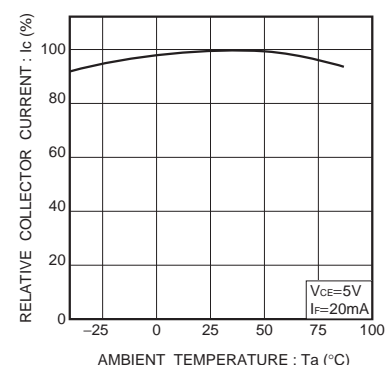
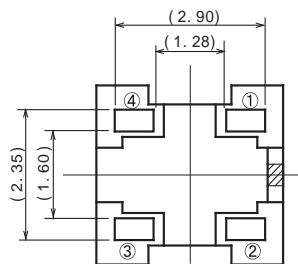
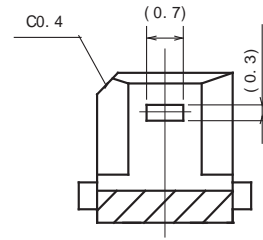
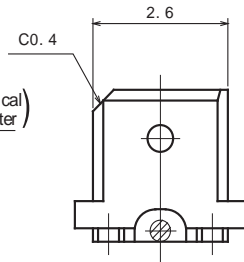
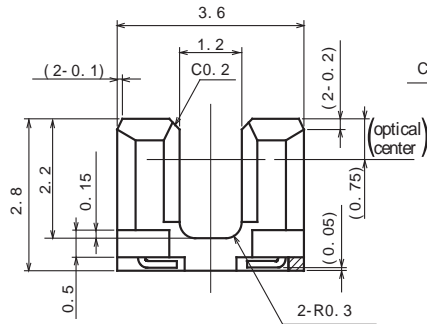
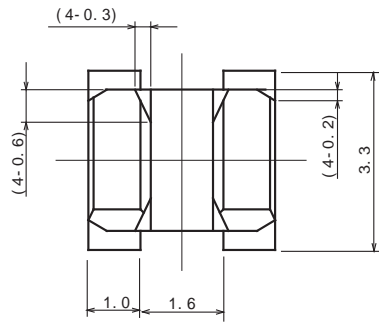


Fig.6 Relative output vs. ambient temperature



Internal Connection diagram
④ Emitter ① Cathode

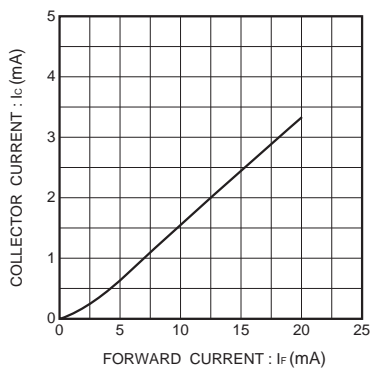
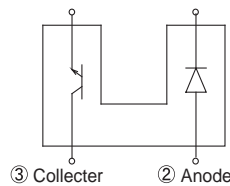


Fig.7 Collector current vs. forward current

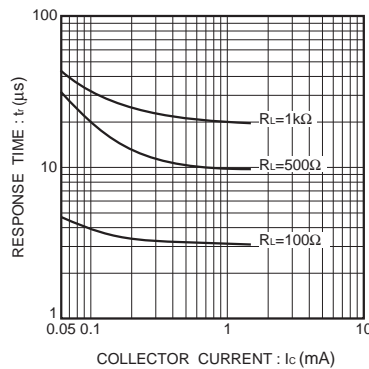


Fig.8 Response time vs. collector current

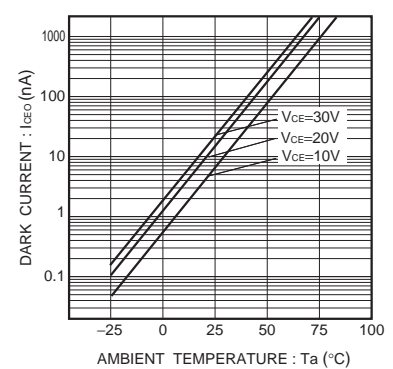


Fig.9 Dark current vs. ambient temperature

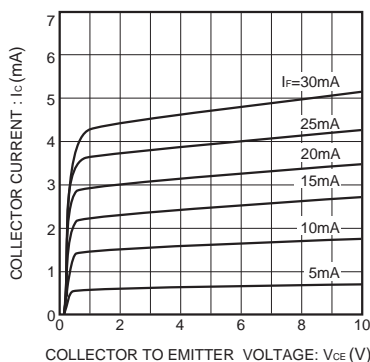


Fig.10 Output characteristics

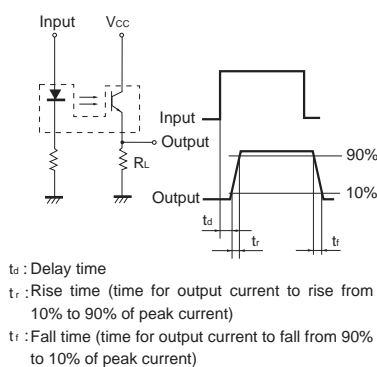


Fig.11 Response time measurement circuit

Notes

No copying or reproduction of this document, in part or in whole, is permitted without the consent of ROHM Co.,Ltd.

The content specified herein is subject to change for improvement without notice.

The content specified herein is for the purpose of introducing ROHM's products (hereinafter "Products"). If you wish to use any such Product, please be sure to refer to the specifications, which can be obtained from ROHM upon request.

Examples of application circuits, circuit constants and any other information contained herein illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.

Great care was taken in ensuring the accuracy of the information specified in this document. However, should you incur any damage arising from any inaccuracy or misprint of such information, ROHM shall bear no responsibility for such damage.

The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM and other parties. ROHM shall bear no responsibility whatsoever for any dispute arising from the use of such technical information.

The Products specified in this document are intended to be used with general-use electronic equipment or devices (such as audio visual equipment, office-automation equipment, communication devices, electronic appliances and amusement devices).

The Products specified in this document are not designed to be radiation tolerant.

While ROHM always makes efforts to enhance the quality and reliability of its Products, a Product may fail or malfunction for a variety of reasons.

Please be sure to implement in your equipment using the Products safety measures to guard against the possibility of physical injury, fire or any other damage caused in the event of the failure of any Product, such as derating, redundancy, fire control and fail-safe designs. ROHM shall bear no responsibility whatsoever for your use of any Product outside of the prescribed scope or not in accordance with the instruction manual.

The Products are not designed or manufactured to be used with any equipment, device or system which requires an extremely high level of reliability the failure or malfunction of which may result in a direct threat to human life or create a risk of human injury (such as a medical instrument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel-controller or other safety device). ROHM shall bear no responsibility in any way for use of any of the Products for the above special purposes. If a Product is intended to be used for any such special purpose, please contact a ROHM sales representative before purchasing.

If you intend to export or ship overseas any Product or technology specified herein that may be controlled under the Foreign Exchange and the Foreign Trade Law, you will be required to obtain a license or permit under the Law.



Thank you for your accessing to ROHM product informations.
More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

<http://www.rohm.com/contact/>

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[ROHM Semiconductor:](#)

[RPI-0129](#)